

# TMBAT49

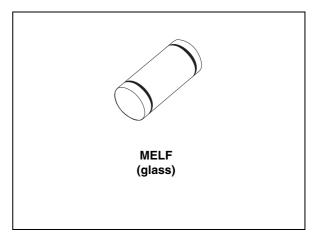
## Small signal Schottky diode

## Features

- very low turn-on voltage
- fast switching

## Description

The TMBAT49 is a general purpose metal to silicon diode. This device has integrated protection against excessive voltage such as electrostatic discharges.



# 1 Characteristics

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	80	V
١ <sub>F</sub>	Forward continuous current	500	mA
I <sub>FRM</sub>	Repetitive peak forward current	3	А
I <sub>FSM</sub>	Surge non repetitive forward current	10	А
T <sub>stg</sub>	Storage temperature range	- 65 to +150	°C
Тj	Operating junction temperature range	- 65 to +125	°C
ΤL	Maximum lead soldering temperature during	260	°C

### Table 1. Absolute ratings (limiting values)

### Table 2.Thermal parameter

Symbol	Parameter	Value	Unit
R <sub>th(j-l)</sub>	Junction to lead	110	°C/W

### Table 3. Static electrical characteristics

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
$I_{R}^{(1)}$	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = 80 V	-	-	200	μΑ
V <sub>F</sub> <sup>(1)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 10 mA	-	-	0.32	v
			I <sub>F</sub> = 100 mA	-	-	0.42	
			I <sub>F</sub> = 1 A	-	-	1	

1. Pulse test:  $t_p \le 300 \ \mu s, \ \delta < 2\%$ 

## Table 4. Dynamic characteristics ( $T_j = 25 \ ^{\circ}C$ )

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
С	C Diode capacitance	E – 1 MHz	V <sub>R</sub> = 0 V	-	120	-	рF
C Diode capacitance		V <sub>R</sub> = 5 V	-	35	-	р	



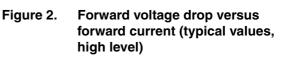
T<sub>i</sub> = 25 °C-

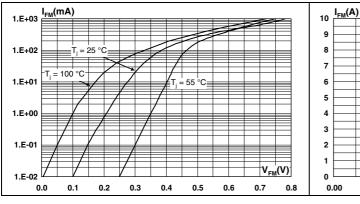
1.25

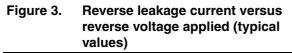
V<sub>FM</sub>(V)

1.50

### Figure 1. Forward voltage drop versus forward current (typical values, low level)







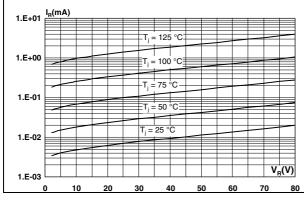


Figure 4. Junction capacitance versus reverse voltage applied (typical values)

0.75

1.00

0.50

0.25

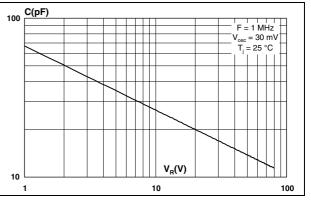
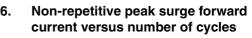
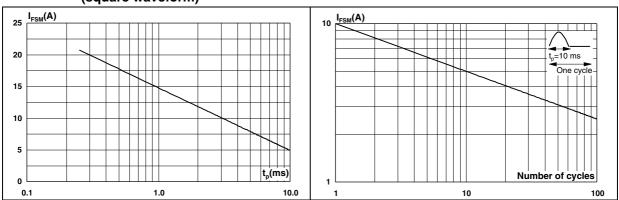


Figure 5. Non-repetitive peak surge forward Figure 6. current versus pulse duration (square waveform)

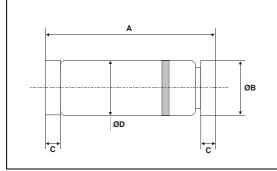




## 2 Package information

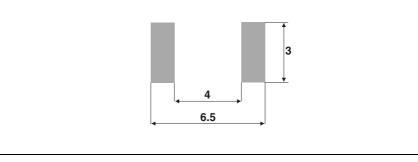
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.





	Dimensions							
Ref.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	4.80		5.20	0.189		0.205		
øΒ	2.50		2.65	0.098		0.104		
С	0.45		0.60	0.018		0.024		
ø D		2.50			0.098			

Figure 7. Footprint (dimensions in mm)





# 3 Ordering information

## Table 6. Ordering information

Order code Marking		Package	Weight	Base qty	Delivery mode
TMBAT49FILM	Cathode ring	MELF (glass)	0.15 g	1500	Bulk

## 4 Revision history

### Table 7.Document revision history

Date	Revision	Changes
Aug-1999	1A	Previous release.
12-Nov-2010 2		Added ECOPACK statement. Updated graphics in Section 1.



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